Octal D Type Flip Flops With 3 State Outputs

HITACHI

ADE-205-010A(Z) Rev. 1 March 1993

Description

The HD74BC374A provides high drivability and operation equal to or better than high speed bipolar standard logic IC by using Bi-CMOS process. The device features low power dissipation that is about 1/5 of high speed bipolar logic IC, when the frequency is 10 MHz. The device has eight edge triger D type flip flop with three state outputs in a 20 pin package. Data at the D inputs meeting set up reguirements, are transferred to the Q outputs on positive going transitions of the clock input. When the latch enable goes low, data at the D inputs will be retained at the outputs until latch enable returns high again. When a high logic level is applied to the output control input, all outputs go to a high impedance state, regardless of what signals are present at the other inputs and the state of the storage elements.

Features

- Input/Output are at high impedance state when power supply is off.
- Built in input pull up circuit can make input pins be open, when not used.
- TTL level input
- Wide operating temperature range Ta = -40 to + 85°C

Function Table

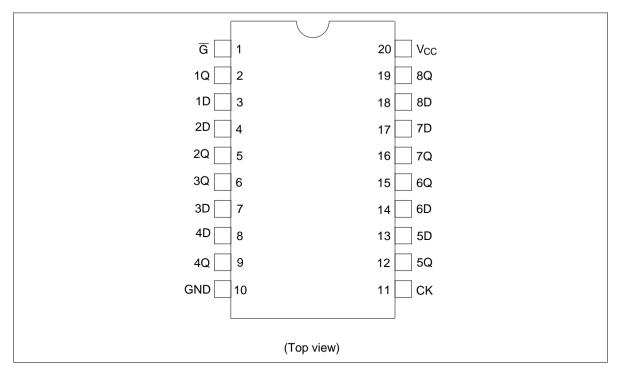
Inputs			Output
G	СК	nD	nQ
Н	Х	Х	Z
L		L	L
L		Н	Н
L		Х	No change
H : High lev	vel		

- L : Low level
- X : Immaterial
- Z : High impedance

 \int : Low to high transition



Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Rating	Unit	
Supply voltage	V _{cc}	-0.5 to +7.0	V	
Input diode current	Ι _{ικ}	±30	mA	
Input voltage	V _{IN}	-0.5 to +7.5	V	
Output voltage	V _{OUT}	-0.5 to +7.5	V	
Off state output voltage	V _{OUT(off)}	-0.5 to +5.5	V	
Storage temperature	Tstg	-65 to +150	°C	

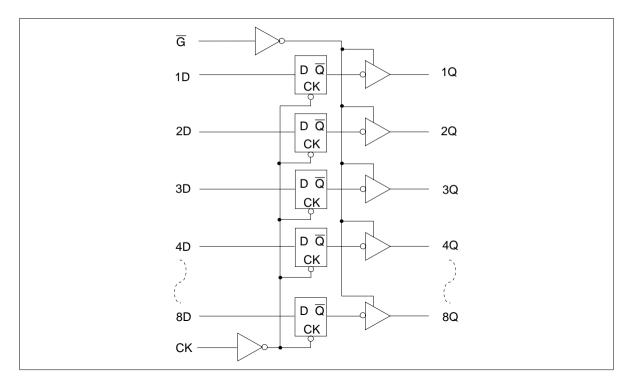
Note: 1. The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Min	Тур	Max	Unit	
Supply voltage	V _{cc}	4.5	5.0	5.5	V	
Input voltage	V _{IN}	0	—	V _{cc}	V	
Output voltage	V _{OUT}	0	—	V _{cc}	V	
Operating temperature	Topr	-40	—	85	°C	
Input rise/fall time*1	t _r , t _f	0		8	ns/V	

Note: 1. This item guarantees maximum limit when one input switches. Waveform: Refer to test circuit of switching characteristics.

Logic Diaglam



Item	Symbol	V _{cc} (V)	Min	Max	Unit	Test Conditions
Input voltage	V _{IH}		2.0	_	V	
	V _{IL}		_	0.8	V	
Output voltage	V _{OH}	4.5	2.4	_	V	I _{он} = –3 mА
		4.5	2.0	—	V	I _{он} = —15 mA
	V _{OL}	4.5	_	0.4	V	I _{oL} = 24 mA
		4.5	_	0.5	V	I _{oL} = 48 mA
Input diode voltage	V _{IK}	4.5		-1.2	V	$I_{IN} = -18 \text{ mA}$
Input current	I,	5.5	—	1.0	μΑ	V _{IN} = 5.5 V
		5.5	—	-250	μΑ	$V_{IN} = 0 V$
		5.5	—	100	μΑ	$V_{IN} = 7.0 V$
Short circuit output current*1	I _{os}	5.5	-100	-225	mA	$V_{IN} = 0 \text{ or } 5.5 \text{ V}$
Off state output current	I _{OZH}	5.5	—	50	μΑ	$V_o = 2.7 V$
	I _{ozL}	5.5	—	-50	μA	$V_{0} = 0.5 V$
Supply current	I _{CCL}	5.5	_	29.5	mA	$V_{IN} = 0 \text{ or } 5.5 \text{ V}$ All output is "L"
	I _{CCH}	5.5	—	2.5	mA	$V_{IN} = 0 \text{ or } 5.5 \text{ V}$ All output is "H"
	I _{ccz}	5.5	_	2.5	mA	$V_{IN} = 0 \text{ or } 5.5 \text{ V}$ All output is "Z"
	I _{CCT} * ²	5.5		1.5	mA	$V_{IN} = 3.4 \text{ or } 0.5 \text{ V}$

Electrical Characteristics (Ta = -40° C to $+85^{\circ}$ C)

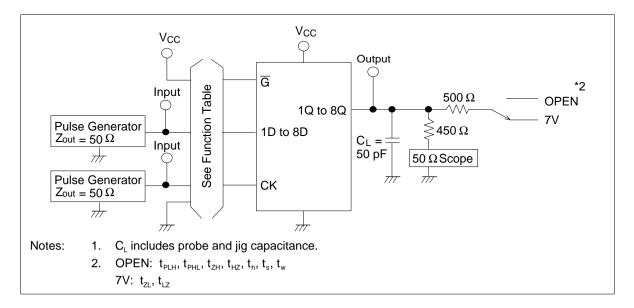
Notes : 1. Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.

2. When input by the TTL level, it shows $I_{\mbox{\tiny CC}}$ increase at per one input pin.

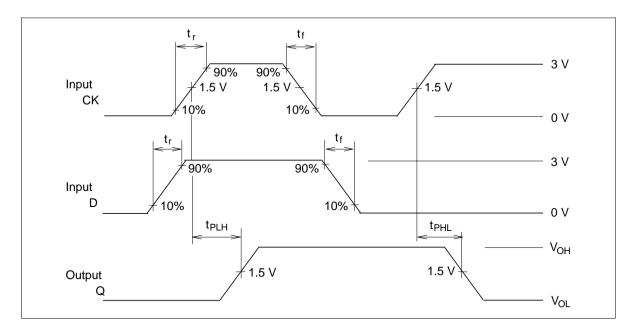
Switching Test Method ($C_L = 50 \text{ pF}$)

		Ta = 25°C V _{cc} = 5.0 V			Ta = −40 to 85°C V _{cc} = 5.0 V ±10%		
Item	Symbol	Min	Max	Min	Max	Unit	Test Conditions
Propagation $CK \rightarrow Q$	t _{PLH}	3.0	8.0	3.0	10.0	ns	See under figure
delay time	t _{PHL}	3.0	8.0	3.0	10.0		
Output enable time	t _{zH}	3.0	9.0	3.0	11.0	ns	_
	t _{zL}	3.0	9.0	3.0	11.0		
Output disable time	t _{HZ}	3.0	8.0	3.0	10.0	ns	_
	t _{LZ}	3.0	8.0	3.0	10.0	_	
Setup time	t _s (H)	2.0	_	2.0	_	ns	_
	t _s (L)	2.0	_	2.0	_	_	
Hold time	t _h (H)	2.0		2.0	_	ns	_
	t _h (L)	2.0		2.0	_	_	
Pulse width	t _w (H)	6.0	_	6.0	_	ns	_
	t _w (L)	6.0	_	6.0	_	_	
Input capacitance	CIN	3.0(Typ)		_		pF	$V_{IN} = V_{CC} \text{ or } GND$
Output capacitance	Co	15.0(Тур)			pF	$V_{o} = V_{cc}$ or GND

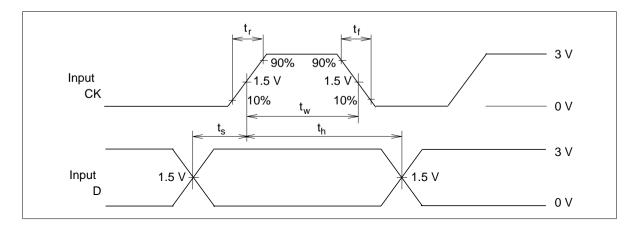
Test Circuit



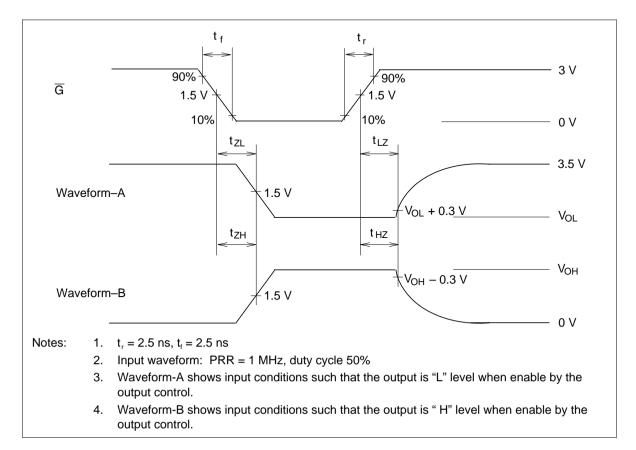
Waveforms-1



Waveforms-2



Waveforms-3



Package Dimensions

Unit: mm

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